

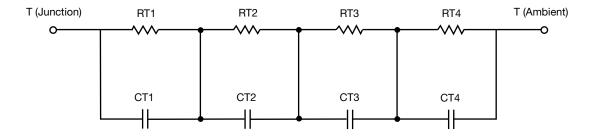
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in PSpice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the PSpice simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the PSpice Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK	CONFIGURATION		
	THERMAL RE	SISTANCE (°C/W)	
Junction to	Ambient	Case	Foot
RT1	n/a	145.7600m	n/a
RT2	n/a	150.6939m	n/a
RT3	n/a	253.5894m	n/a
RT4	n/a	149.9569m	n/a
	THERMAL CAPAC	CITANCE (Joules/°C)	
Junction to	Ambient	Case	Foot
CT1	n/a	30.0871m	n/a
CT2	n/a	20.3743m	n/a
CT3	n/a	129.8790m	n/a
CT4	n/a	28.4851m	n/a

Note

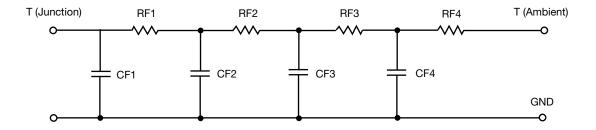
n/a indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

Revision: 13-Sep-16 1 Document Number: 91937



R-C THERMAL MODEL FOR FILTER CONFIGURATION



THERMAL RESISTANCE (°C/W)					
Junction to	Ambient	Case	Foot		
RF1	n/a	366.2576m	n/a		
RF2	n/a	136.4127m	n/a		
RF3	n/a	100.8855m	n/a		
RF4	n/a	96.4442m	n/a		
	THERMAL CAPAC	CITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot		
CF1	n/a	7.6087m	n/a		
CF2	n/a	6.2720m	n/a		
CF3	n/a	142.0064m	n/a		
CF4	n/a	2.8489m	n/a		

Note

• n/a indicates not applicable





www.vishay.com

Vishay Siliconix

